



### **60V N-CHANNEL ENHANCEMENT MODE MOSFET**

## **Product Summary**

V <sub>(BR)DSS</sub>	R <sub>DS(ON)</sub> Max	I <sub>D</sub> Max T <sub>A</sub> = +25°C		
00)/	40mΩ @ V <sub>GS</sub> = 10V	5.0A		
60V	$55mΩ @ V_{GS} = 4.5V$	4.2A		

### **Description**

This new generation MOSFET is designed to minimize the on-state resistance (R<sub>DS(ON)</sub>), yet maintain superior switching performance, making it ideal for high efficiency power management applications.

## **Applications**

- Motor Control
- Transformer Driving Switch
- DC-DC Converters
- Power Management Functions
- Uninterrupted Power Supply

## **Features**

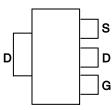
- 100% Unclamped Inductive Switch (UIS) Test in Production
- Low On-Resistance
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### **Mechanical Data**

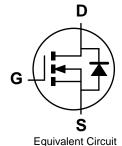
- Case: SOT223
- Case Material: Molded Plastic, "Green" Molding Compound.
   UL Flammability Classification Rating 94V-0 (Note 1)
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals Connections: See Diagram Below
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.112 grams (Approximate)







Pin Out - Top View



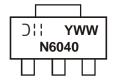
### **Ordering Information** (Note 4)

Part Number	Marking	Reel Size (inches)	Quantity per Reel
DMN6040SE-13	N6040	13	2,500

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

# **Marking Information**



N6040 = Product Type Marking Code

);; = Manufacturer's Marking

YWW = Date Code Marking

Y = Year (ex: 16 = 2016)

WW = Week (01 - 53)



# 

Characteristic	Symbol	Value	Units		
Drain-Source Voltage	$V_{DSS}$	60	V		
Gate-Source Voltage	$V_{GSS}$	±20	V		
Continuous Dusin Compant (Nata C) V	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	I <sub>D</sub>	5.0 4.0	А
Continuous Drain Current (Note 6) V <sub>GS</sub> = 10V	t < 10s	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	ID	7.1 5.5	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I <sub>DM</sub>	30	Α		
Maximum Body Diode Continuous Current	Is	3.4	Α		
Avalanche Current (Note 7) L = 0.1mH	I <sub>AS</sub>	14.2	Α		
Avalanche Energy (Note 7) L = 0.1mH	E <sub>AS</sub>	10	mJ		

# Thermal Characteristics ( $@T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic	Symbol	Value	Units	
Total Power Dissipation (Note 5)	TA = +25°C	C	1.2	W
Total Power Dissipation (Note 5)	Ta = +70°C	$P_{D}$	0.7	
Thormal Posistance, Junction to Ambient (Note 5)	Steady State	C	106	°C/W
Thermal Resistance, Junction to Ambient (Note 5)	t < 10s	$R_{\theta JA}$	53	
Total Power Discinstion (Note 6)	Ta = +25°C	0	2	W
Total Power Dissipation (Note 6)	Ta = +70°C	$P_{D}$	1.2	
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	c	65	°C/W
Themal Resistance, Junction to Ambient (Note 6)	t < 10s	$R_{\theta JA}$	34	
Thermal Resistance, Junction to Case (Note 6)	R <sub>0</sub> JC	9	°C/W	
Operating and Storage Temperature Range	$T_{J,}T_{STG}$	-55 to +150	°C	

# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Observation of the	0	Min	T		11-24	Total Constitution	
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)			1	1			
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	60	_	_	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	_	1	μΑ	$V_{DS} = 60V, V_{GS} = 0V$	
Gate-Source Leakage	$I_{GSS}$	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1	_	3	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
Static Drain-Source On-Resistance			30	40	mΩ	$V_{GS} = 10V, I_D = 12A$	
Static Dialif-Source Off-Resistance	R <sub>DS(ON)</sub>	_	35	55	11152	$V_{GS} = 4.5V, I_D = 6A$	
Diode Forward Voltage	$V_{SD}$	_	0.7	1.2	V	$V_{GS} = 0V, I_{S} = 1A$	
DYNAMIC CHARACTERISTICS (Note 9)	_						
Input Capacitance	C <sub>ISS</sub>		1,287	_		V <sub>DS</sub> = 25V, V <sub>GS</sub> = 0V f = 1.0MHz	
Output Capacitance	Coss		57	_	pF		
Reverse Transfer Capacitance	C <sub>RSS</sub>	_	44	_			
Gate Resistance	$R_{G}$		1.2	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge (V <sub>GS</sub> = 10V)	$Q_{G}$	_	22.4	_			
Total Gate Charge (V <sub>GS</sub> = 4.5V)	$Q_G$	_	10.4	_	nC	V <sub>DS</sub> = 30V, I <sub>D</sub> = 4.3A	
Gate-Source Charge	Q <sub>GS</sub>	_	4.9	_	110		
Gate-Drain Charge	$Q_{GD}$	_	3.0	_			
Turn-On Delay Time	t <sub>D(ON)</sub>	_	6.6	_		$V_{GS}=10V,V_{DD}=30V,R_G=6\Omega,$ $I_D=4.3A$	
Turn-On Rise Time	t <sub>R</sub>	_	8.1	_			
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	20.1	_	ns		
Turn-Off Fall Time	t <sub>F</sub>	_	4.0				
Body Diode Reverse Recovery Time	t <sub>RR</sub>		18		ns	$I_S = 4.3A$ , di/dt = 100A/ $\mu$ s	
Body Diode Reverse Recovery Charge	$Q_{RR}$	_	11.9	_	nC	$I_S = 4.3A$ , di/dt = 100A/ $\mu$ s	

5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

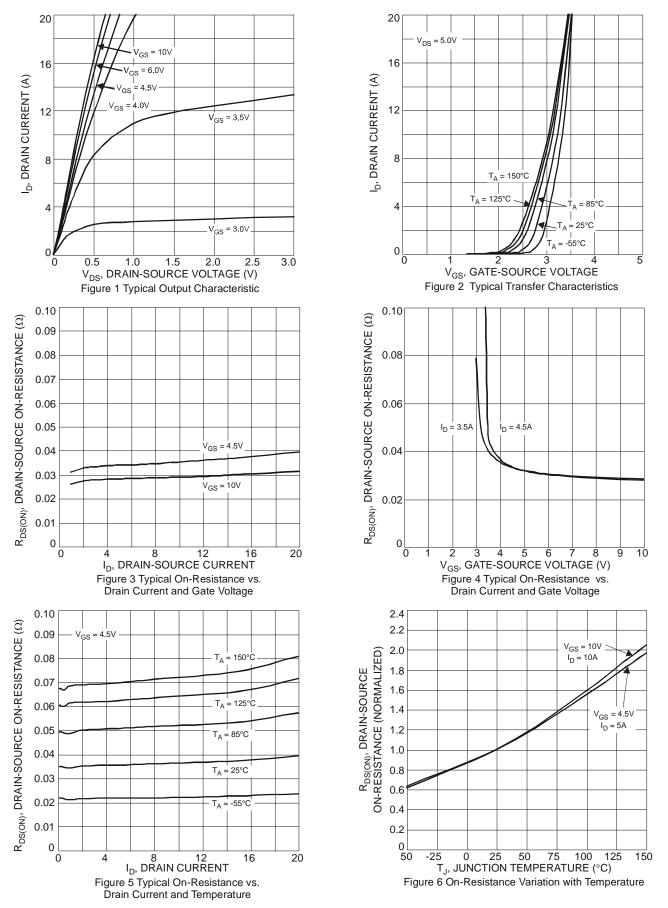
<sup>6.</sup> Device mounted on FR-4 substrate PC board, 2oz copper, with thermal vias to bottom layer 1-inch square copper plate.

<sup>7.</sup> I<sub>AS</sub> and E<sub>AS</sub> rating are based on low frequency and duty cycles to keep  $T_J = +25$ °C.

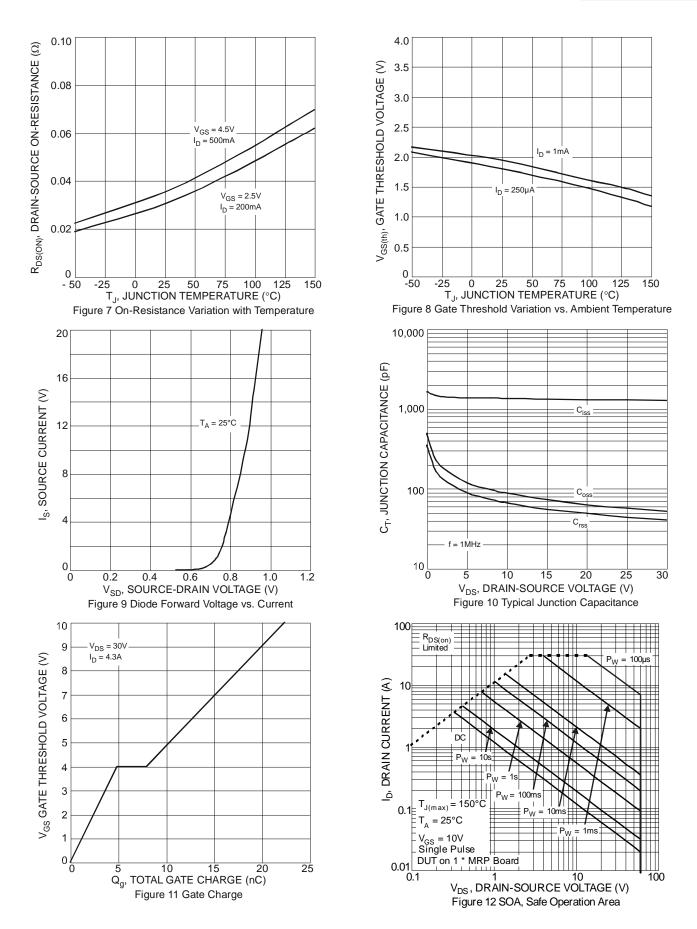
<sup>8.</sup> Short duration pulse test used to minimize self-heating effect.

<sup>9.</sup> Guaranteed by design. Not subject to product testing.

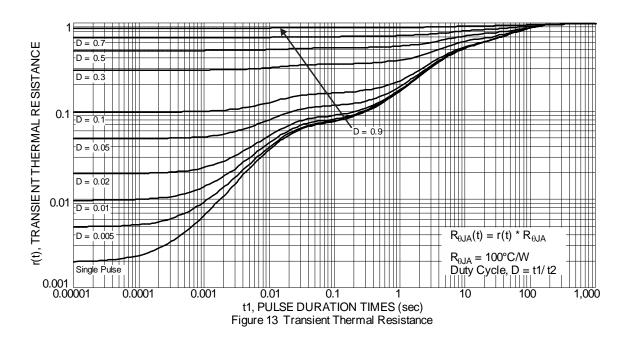








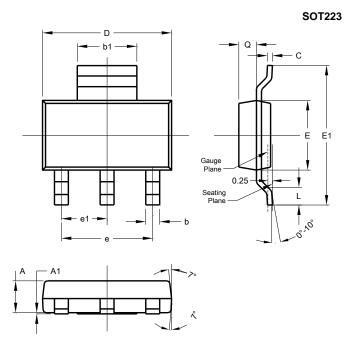






## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

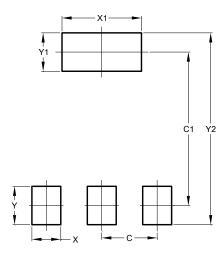


SOT223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A1	0.010	0.15	0.05		
b	0.60	0.80	0.70		
b1	2.90	3.10	3.00		
C	0.20	0.30	0.25		
D	6.45	6.55	6.50		
Е	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е	_	_	4.60		
e1	_	_	2.30		
L	0.85	1.05	0.95		
Ø	0.84	0.94	0.89		
All Dimensions in mm					

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### **SOT223**



Dimensions	Value (in mm)			
С	2.30			
C1	6.40			
Х	1.20			
X1	3.30			
Y	1.60			
Y1	1.60			
Y2	8.00			

July 2016



#### **IMPORTANT NOTICE**

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

### **LIFE SUPPORT**

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
  - 1. are intended to implant into the body, or
  - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2016, Diodes Incorporated

www.diodes.com